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[MCC250-14IO1](#)

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Thyristor Modules

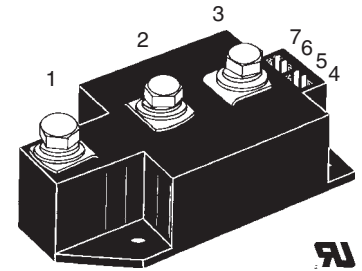
Thyristor/Diode Modules

$$I_{TRMS} = 2 \times 450 \text{ A}$$

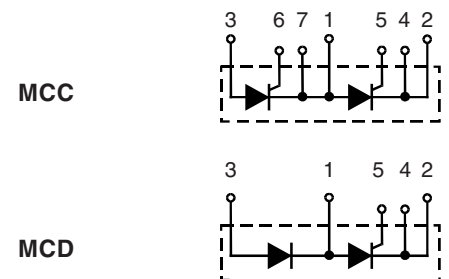
$$I_{TAVM} = 2 \times 287 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V	Type	Version 1	Version 1
900	800	MCC 250-08io1	MCC 250-08io1	MCD 250-08io1
1300	1200	MCC 250-12io1	MCC 250-12io1	MCD 250-12io1
1500	1400	MCC 250-14io1	MCC 250-14io1	MCD 250-14io1
1700	1600	MCC 250-16io1	MCC 250-16io1	MCD 250-16io1
1900	1800	MCC 250-18io1	MCC 250-18io1	MCD 250-18io1



Symbol	Conditions	Maximum Ratings	
I_{TRMS}, I_{FRMS}	$T_{VJ} = T_{VJM}$	450	A
I_{TAVM}, I_{FAVM}	$T_C = 85^\circ\text{C}; 180^\circ \text{ sine}$	287	A
I_{TSM}, I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$	9000 A
		$t = 8.3 \text{ ms (60 Hz), sine}$	9600 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$	7800 A
		$t = 8.3 \text{ ms (60 Hz), sine}$	8500 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$	405 000 A^2s
		$t = 8.3 \text{ ms (60 Hz), sine}$	380 000 A^2s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM};$ $f = 50 \text{ Hz}; t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$	repetitive, $I_T = 860 \text{ A}$	100 $\text{A}/\mu\text{s}$
		$I_G = 1 \text{ A};$ $di_G/dt = 1 \text{ A}/\mu\text{s}$	non repetitive, $I_T = 290 \text{ A}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM};$ $R_{GK} = \infty; \text{method 1 (linear voltage rise)}$	$V_{DR} = 2/3 V_{DRM}$	1000 $\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM};$ $I_T = I_{TAVM};$	$t_p = 30 \mu\text{s}$	120 W
		$t_p = 500 \mu\text{s}$	60 W
P_{GAV}			20 W
V_{RGM}			10 V
T_{VJ}		-40...+140	$^\circ\text{C}$
T_{VJM}		140	$^\circ\text{C}$
T_{stg}		-40...+125	$^\circ\text{C}$
V_{ISOL}	50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA};$	$t = 1 \text{ min}$	3000 V~
		$t = 1 \text{ s}$	3600 V~
M_d	Mounting torque (M5) Terminal connection torque (M8)	2.5-5/22-44	Nm/lb.in.
		12-15/106-132	Nm/lb.in.
Weight	Typical including screws	320	g



Features

- International standard package
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Keyed gate/cathode twin pins

Applications

- Motor control
- Power converter
- Heat and temperature control for industrial furnaces and chemical processes
- Lighting control
- Contactless switches

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.
 IXYS reserves the right to change limits, test conditions and dimensions

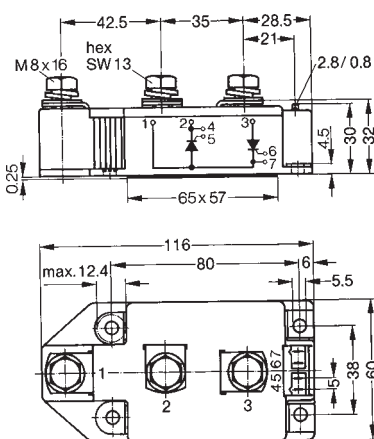
Symbol	Conditions	Characteristic Values
I_{RRM}	$T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$	70 mA
I_{DRM}		40 mA
V_T, V_F	$I_T/I_F = 600 A; T_{VJ} = 25^\circ C$	1.36 V
V_{T0}	For power-loss calculations only ($T_{VJ} = 140^\circ C$)	0.85 V
r_T		0.82 mΩ
V_{GT}	$V_D = 6 V; T_{VJ} = 25^\circ C$	2 V
	$T_{VJ} = -40^\circ C$	3 V
I_{GT}	$V_D = 6 V; T_{VJ} = 25^\circ C$	150 mA
	$T_{VJ} = -40^\circ C$	200 mA
V_{GD}	$T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$	0.25 V
I_{GD}		10 mA
I_L	$T_{VJ} = 25^\circ C; t_p = 30 \mu s; V_D = 6 V$ $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$	200 mA
I_H	$T_{VJ} = 25^\circ C; V_D = 6 V; R_{GK} = \infty$	150 mA
t_{gd}	$T_{VJ} = 25^\circ C; V_D = \frac{1}{2} V_{DRM}$ $I_G = 1 A; di_G/dt = 1 A/\mu s$	2 μs
t_q	$T_{VJ} = T_{VJM}; I_T = 300 A, t_p = 200 \mu s; -di/dt = 10 A/\mu s$ $V_R = 100 V; dv/dt = 50 V/\mu s; V_D = \frac{2}{3} V_{DRM}$	typ. 200 μs
Q_S	$T_{VJ} = 125^\circ C; I_T/I_F = 400 A, -di/dt = 50 A/\mu s$	760 μC
I_{RM}		275 A
R_{thJC}	per thyristor/diode; DC current per module	0.129 KW
R_{thJK}	per thyristor/diode; DC current per module	0.0645 KW
	other values see Fig. 8/9	0.169 KW
		0.0845 KW
d_S	Creepage distance on surface	12.7 mm
d_A	Strike distance through air	9.6 mm
a	Maximum allowable acceleration	50 m/s ²

Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red
 Type **ZY 180L** (L = Left for pin pair 4/5) } UL 758, style 1385,
 Type **ZY 180R** (R = right for pin pair 6/7) } CSA class 5851, guide 460-1-1

Dimensions in mm (1 mm = 0.0394")

MCC



MCD

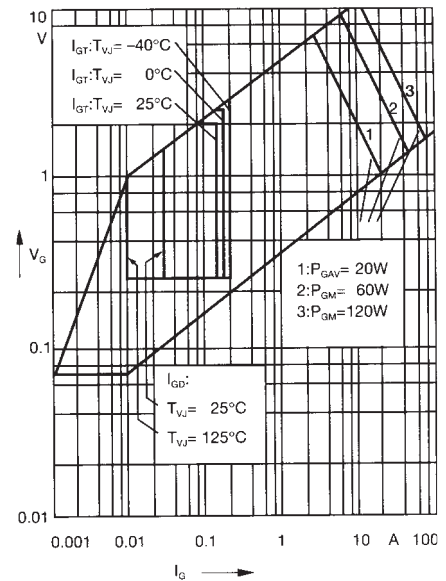
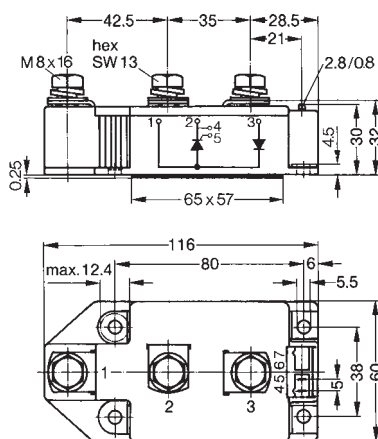


Fig. 1 Gate trigger characteristics

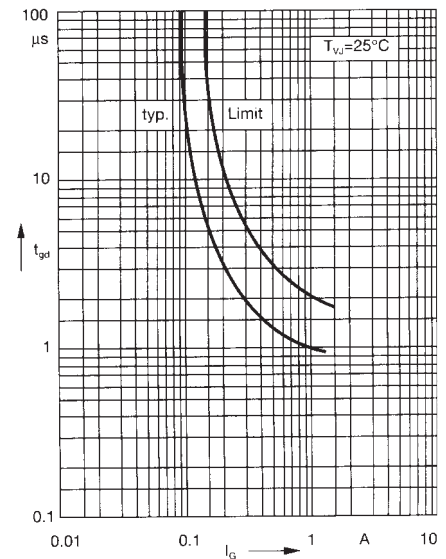
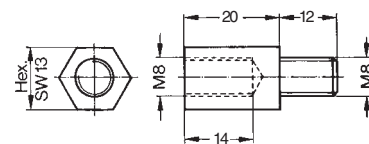


Fig. 2 Gate trigger delay time

Threaded spacer for higher Anode/Cathode construction:
 Type **ZY 250**, material brass



IXYS **MCC 250**
MCD 250

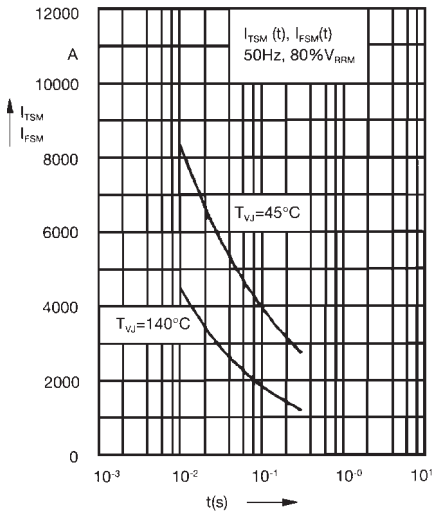


Fig. 3 Surge overload current
 I_{TSM} , I_{FSM} : Crest value, t: duration

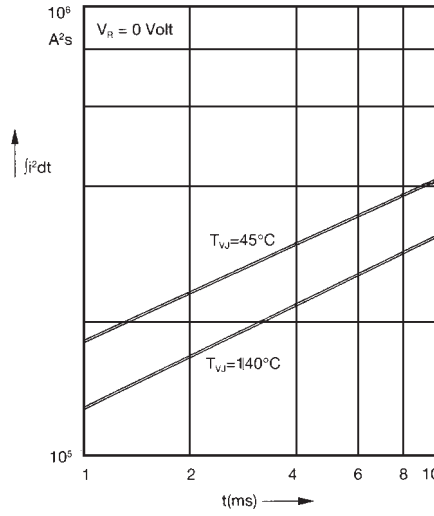


Fig. 4 $\int i^2 dt$ versus time (1-10 ms)

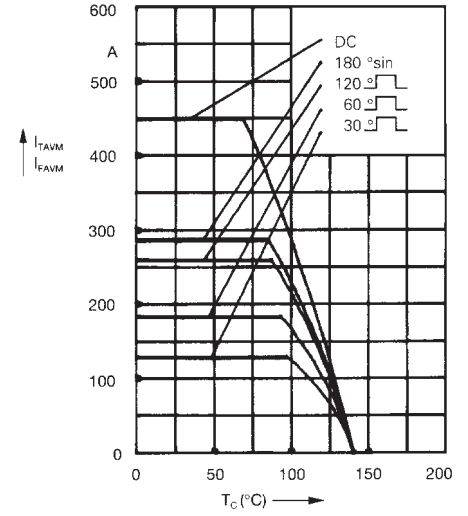


Fig. 4a Maximum forward current at case temperature

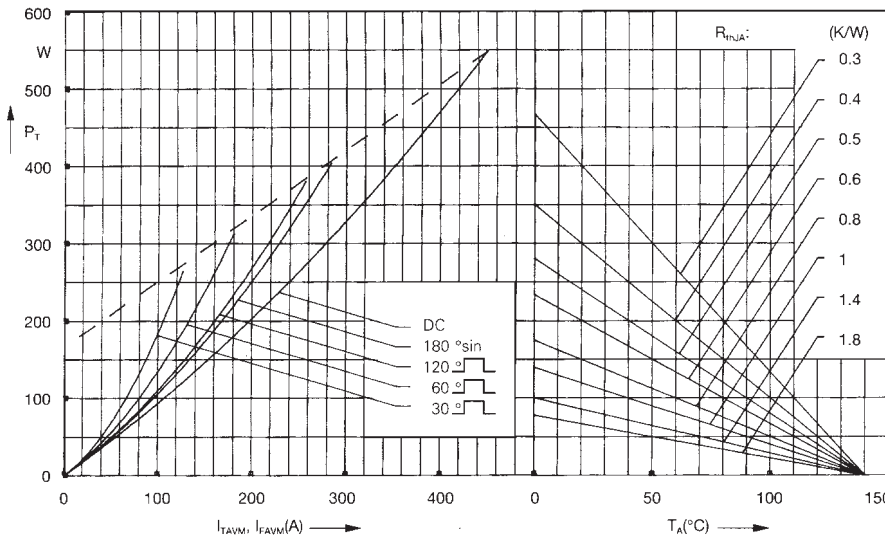


Fig. 5 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

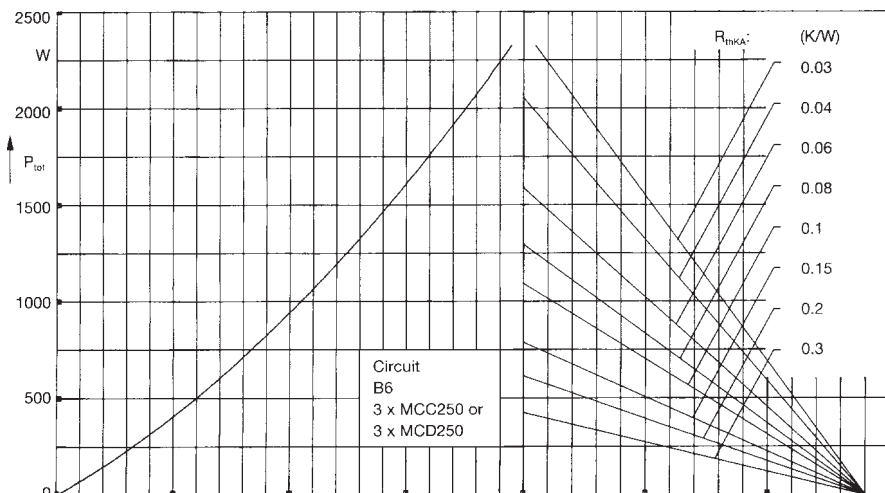


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

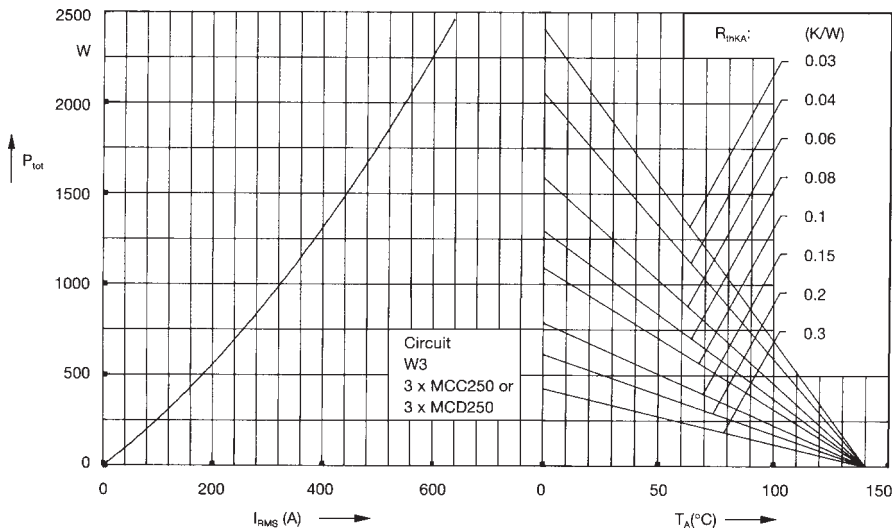


Fig. 7 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

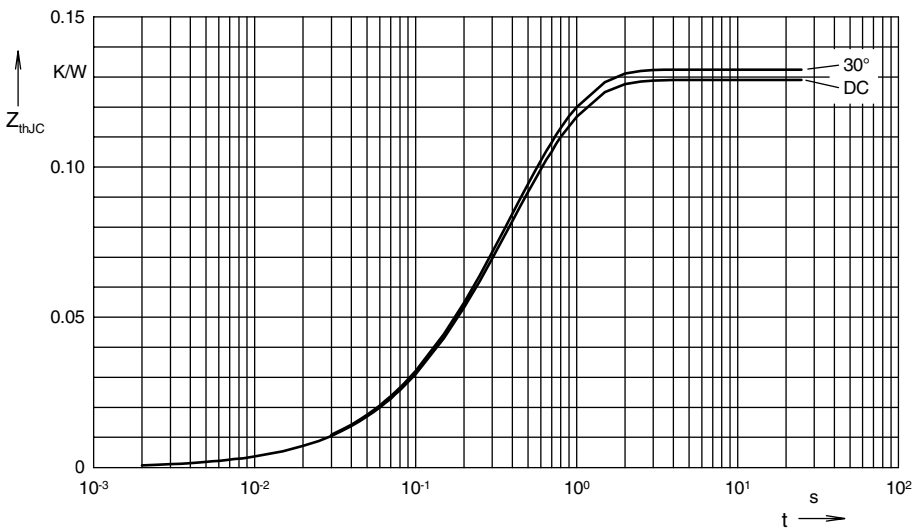


Fig. 8 Transient thermal impedance junction to case (per thyristor or diode)

R_{thJC} for various conduction angles d :

d	R_{thJC} (K/W)
DC	0.129
180°	0.131
120°	0.131
60°	0.132
30°	0.132

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0035	0.099
2	0.0165	0.168
3	0.1091	0.456

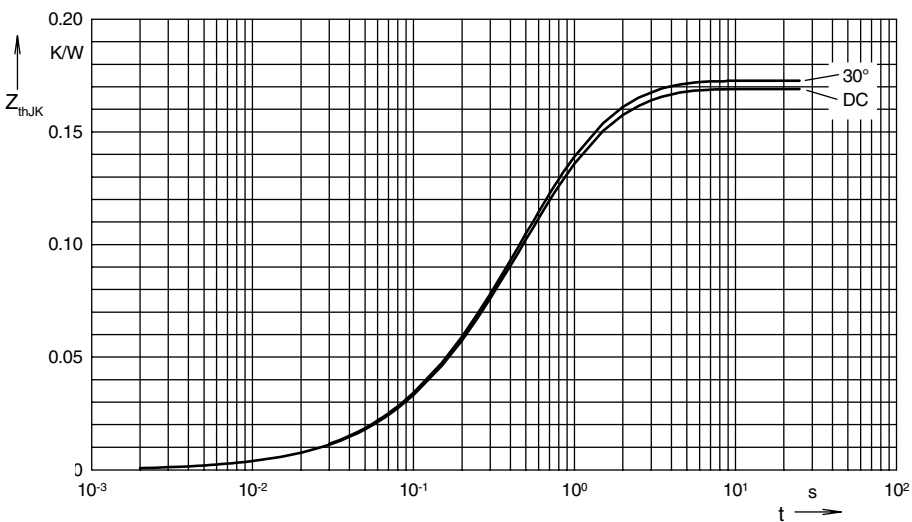


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor or diode)

R_{thJK} for various conduction angles d :

d	R_{thJK} (K/W)
DC	0.169
180°	0.171
120°	0.172
60°	0.172
30°	0.173

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0033	0.099
2	0.0159	0.168
3	0.1053	0.456
4	0.04	1.36